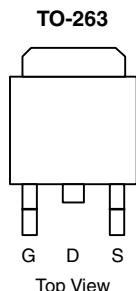


## N Channel 100 V (D-S) MOSFET

PRODUCT SUMMARY			
$V_{(BR)DSS}$ (V)	$R_{DS(on)}$ ( $\Omega$ )	$I_D$ (A)	$Q_g$ (Typ)
100	0.0082 at $V_{GS} = 10$ V	90 <sup>d</sup>	97

### FEATURES

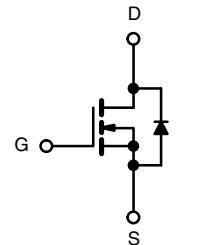
- TrenchFET® Power MOSFETs
- 175 °C Junction Temperature
- 100 %  $R_g$  and UIS Tested
- Compliant to RoHS Directive 2002/95/EC



Ordering Information: SUM90N10-8m2P-E3 (Lead (Pb)-free)

### APPLICATIONS

- Power Supply
  - Secondary Synchronous Rectification
- Industrial
- Primary Switch



ABSOLUTE MAXIMUM RATINGS ( $T_C = 25$ °C, unless otherwise noted)			
Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	100	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	
Continuous Drain Current ( $T_J = 175$ °C)	$I_D$	90 <sup>d</sup>	A
		90 <sup>d</sup>	
Pulsed Drain Current	$I_{DM}$	240	
Avalanche Current	$I_{AS}$	60	
Single Avalanche Energy <sup>a</sup>	$E_{AS}$	180	mJ
Maximum Power Dissipation <sup>a</sup>	$P_D$	300 <sup>b</sup>	W
		3.75	
Operating Junction and Storage Temperature Range	$T_J, T_{stg}$	- 55 to 175	°C

THERMAL RESISTANCE RATINGS			
Parameter	Symbol	Limit	Unit
Junction-to-Ambient (PCB Mount) <sup>c</sup>	$R_{thJA}$	40	°C/W
Junction-to-Case (Drain)	$R_{thJC}$	0.5	

Notes:

- a. Duty cycle  $\leq 1$  %.
- b. See SOA curve for voltage derating.
- c. When mounted on 1" square PCB (FR-4 material).
- d. Package limited.

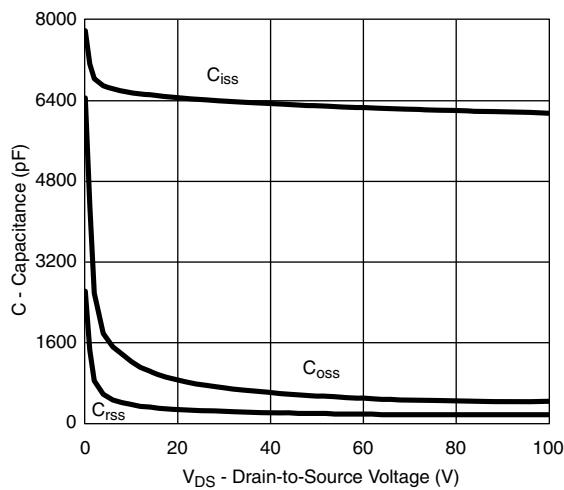
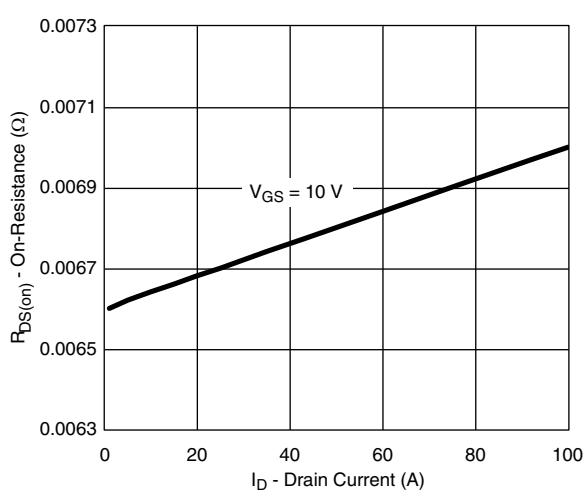
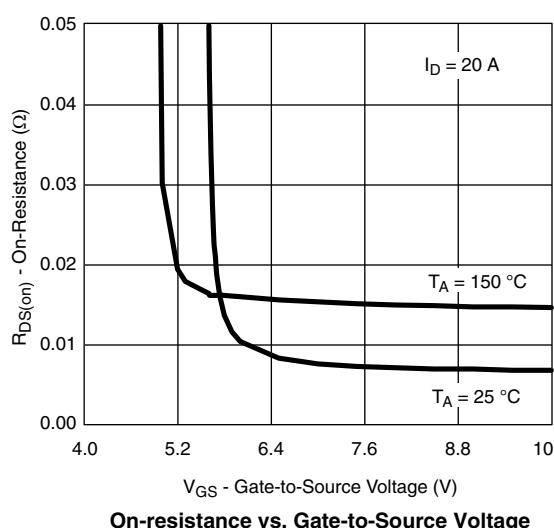
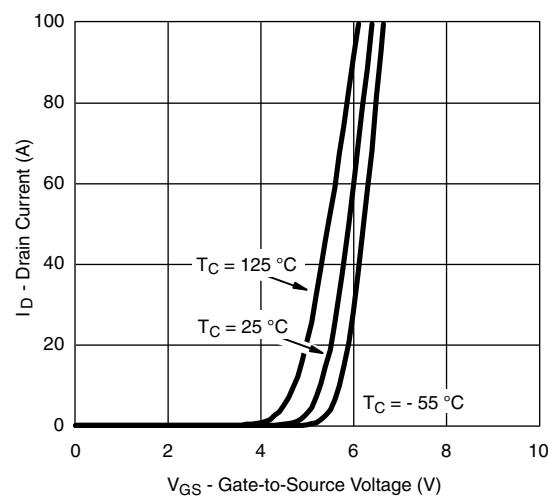
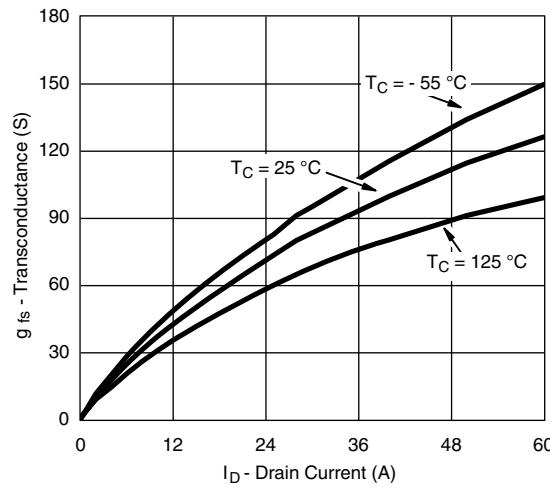
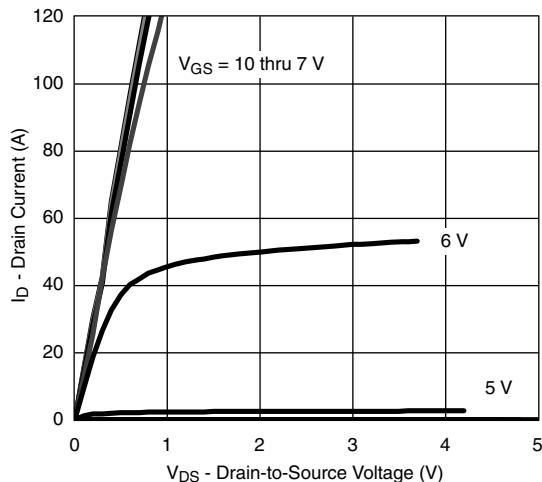
**SPECIFICATIONS** ( $T_J = 25^\circ\text{C}$ , unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
<b>Static</b>						
Drain-Source Breakdown Voltage	$V_{(\text{BR})\text{DSS}}$	$V_{\text{DS}} = 0 \text{ V}, I_D = 250 \mu\text{A}$	100			V
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}} = V_{\text{GS}}, I_D = 250 \mu\text{A}$	2.5		4.5	
Gate-Body Leakage	$I_{\text{GSS}}$	$V_{\text{DS}} = 0 \text{ V}, V_{\text{GS}} = \pm 20 \text{ V}$			$\pm 250$	nA
Zero Gate Voltage Drain Current	$I_{\text{DSS}}$	$V_{\text{DS}} = 100 \text{ V}, V_{\text{GS}} = 0 \text{ V}$			1	$\mu\text{A}$
		$V_{\text{DS}} = 100 \text{ V}, V_{\text{GS}} = 0 \text{ V}, T_J = 125^\circ\text{C}$			50	
		$V_{\text{DS}} = 100 \text{ V}, V_{\text{GS}} = 0 \text{ V}, T_J = 150^\circ\text{C}$			250	
On-State Drain Current <sup>a</sup>	$I_{\text{D}(\text{on})}$	$V_{\text{DS}} \geq 10 \text{ V}, V_{\text{GS}} = 10 \text{ V}$	70			A
Drain-Source On-State Resistance <sup>a</sup>	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}} = 10 \text{ V}, I_D = 20 \text{ A}$		0.0067	0.0082	$\Omega$
		$V_{\text{GS}} = 10 \text{ V}, I_D = 20 \text{ A}, T_J = 125^\circ\text{C}$		0.0127	0.0170	
Forward Transconductance <sup>a</sup>	$g_{\text{fs}}$	$V_{\text{DS}} = 15 \text{ V}, I_D = 20 \text{ A}$		62		S
<b>Dynamic<sup>b</sup></b>						
Input Capacitance	$C_{\text{iss}}$	$V_{\text{GS}} = 0 \text{ V}, V_{\text{DS}} = 50 \text{ V}, f = 1 \text{ MHz}$		6290		pF
Output Capacitance	$C_{\text{oss}}$			535		
Reverse Transfer Capacitance	$C_{\text{rss}}$			182		
Total Gate Charge <sup>c</sup>	$Q_g$	$V_{\text{DS}} = 50 \text{ V}, V_{\text{GS}} = 10 \text{ V}, I_D = 85 \text{ A}$		97	150	nC
Gate-Source Charge <sup>c</sup>	$Q_{\text{gs}}$			32		
Gate-Drain Charge <sup>c</sup>	$Q_{\text{gd}}$			25		
Gate Resistance	$R_g$	$f = 1 \text{ MHz}$	0.28	1.4	2.8	$\Omega$
Turn-On Delay Time <sup>c</sup>	$t_{\text{d}(\text{on})}$	$V_{\text{DD}} = 50 \text{ V}, R_L = 0.588 \Omega$ $I_D \geq 85 \text{ A}, V_{\text{GEN}} = 10 \text{ V}, R_g = 1 \Omega$		23	35	ns
Rise Time <sup>c</sup>	$t_r$			17	26	
Turn-Off Delay Time <sup>c</sup>	$t_{\text{d}(\text{off})}$			34	52	
Fall Time <sup>c</sup>	$t_f$			9	18	
<b>Source-Drain Diode Ratings and Characteristics</b> ( $T_C = 25^\circ\text{C}$ ) <sup>b</sup>						
Continuous Current	$I_S$				85	A
Pulsed Current	$I_{\text{SM}}$				240	
Forward Voltage <sup>a</sup>	$V_{\text{SD}}$	$I_F = 30 \text{ A}, V_{\text{GS}} = 0 \text{ V}$		0.85	1.5	V
Reverse Recovery Time	$t_{\text{rr}}$	$I_F = 75 \text{ A}, di/dt = 100 \text{ A}/\mu\text{s}$		61	100	ns
Peak Reverse Recovery Current	$I_{\text{RRM}(\text{REC})}$			3	4.5	A
Reverse Recovery Charge	$Q_{\text{rr}}$			91	130	$\mu\text{C}$

Notes:

- a. Pulse test; pulse width  $\leq 300 \mu\text{s}$ , duty cycle  $\leq 2\%$ .
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

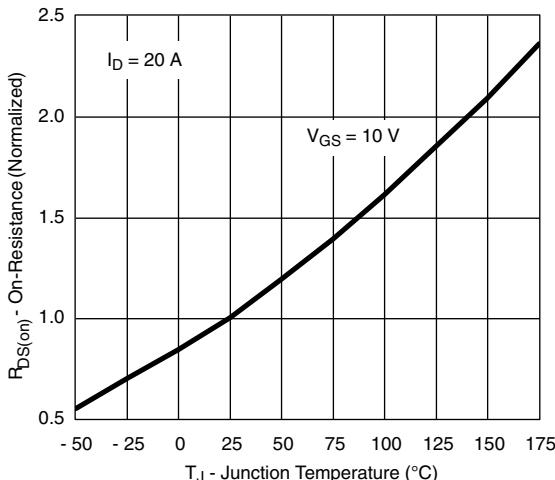
**TYPICAL CHARACTERISTICS** (25 °C, unless otherwise noted)


# SUM90N10-8m2P

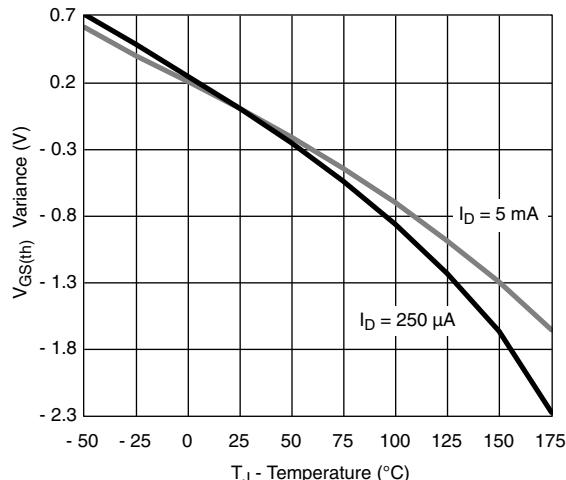
Vishay Siliconix



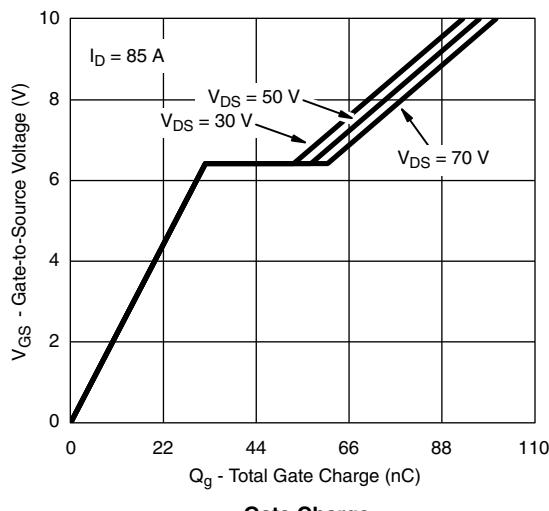
## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



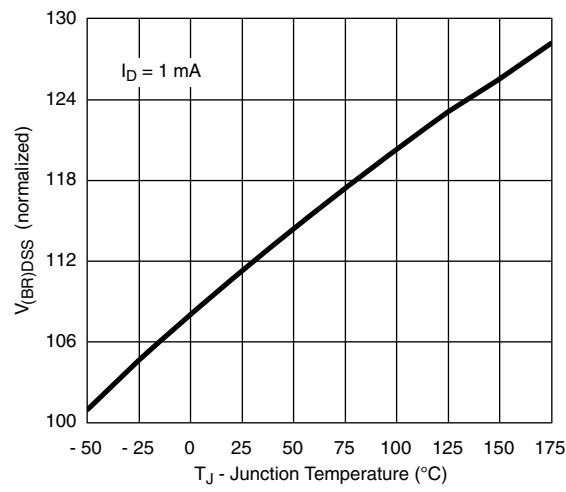
On-Resistance vs. Junction Temperature



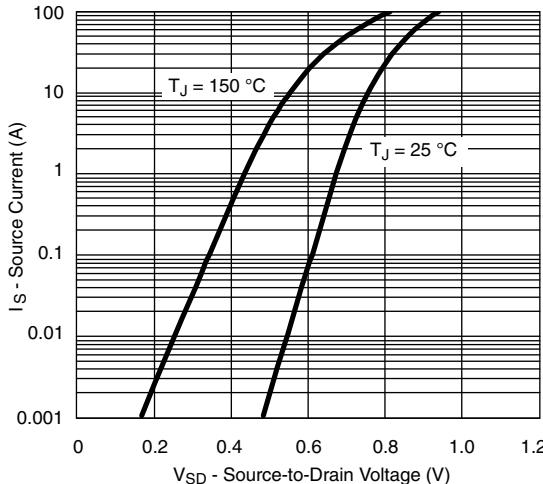
Threshold Voltage



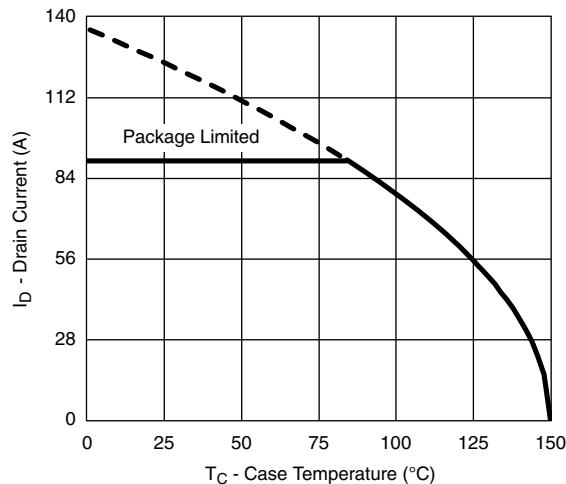
Gate Charge



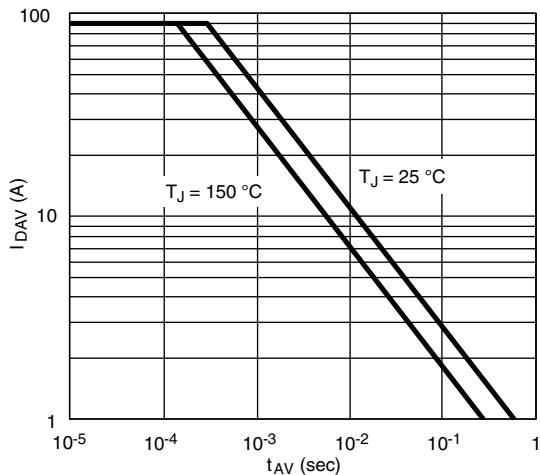
Drain Source Breakdown vs. Junction Temperature



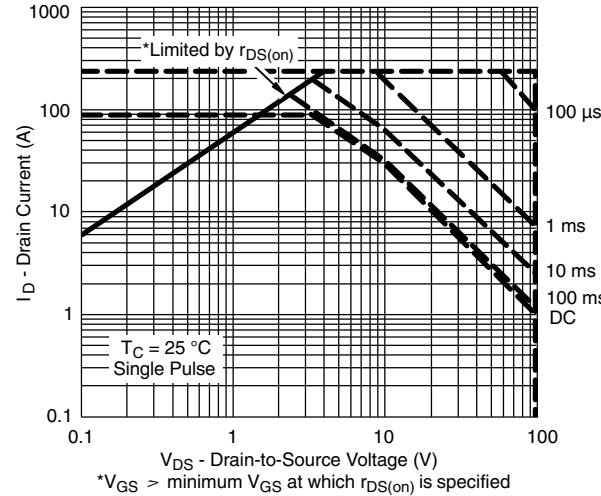
Source-Drain Diode Forward Voltage



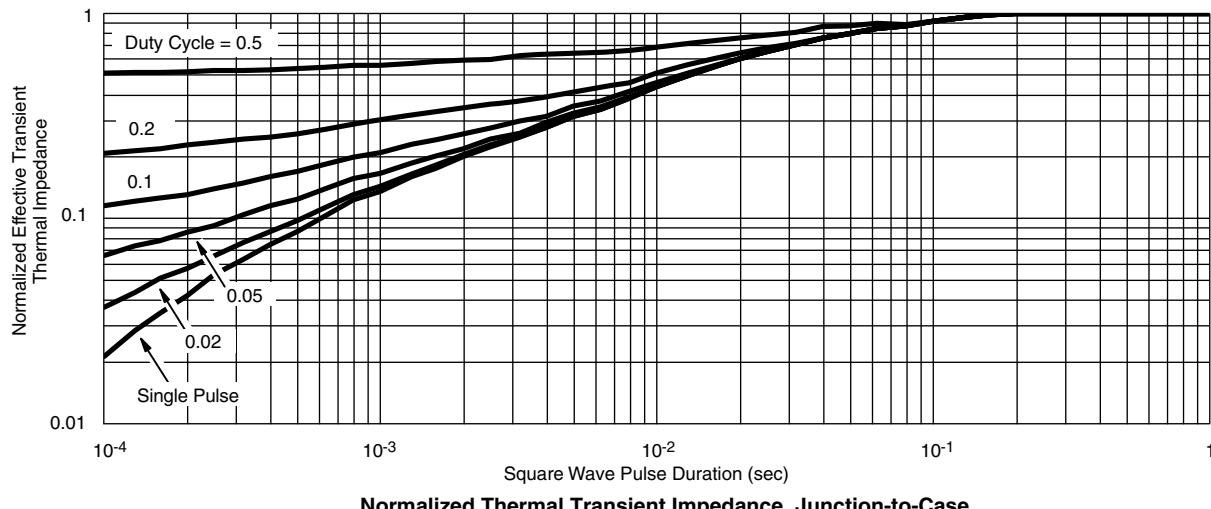
Maximum Drain Current vs. Case Temperature

**TYPICAL CHARACTERISTICS** (25 °C, unless otherwise noted)


Single Pulse Avalanche Current Capability vs. Time



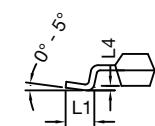
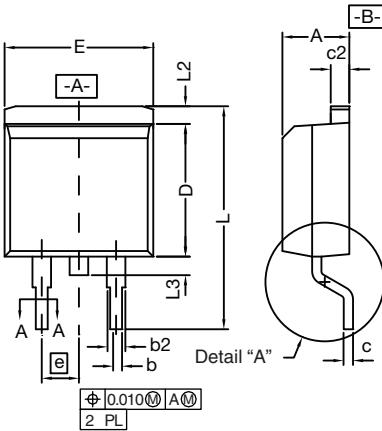
Safe Operating Area



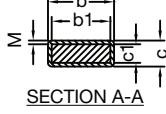
Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see [www.vishay.com/ppg?74643](http://www.vishay.com/ppg?74643).

### TO-263 (D<sup>2</sup>PAK): 3-LEAD



DETAIL A (ROTATED 90°)



SECTION A-A

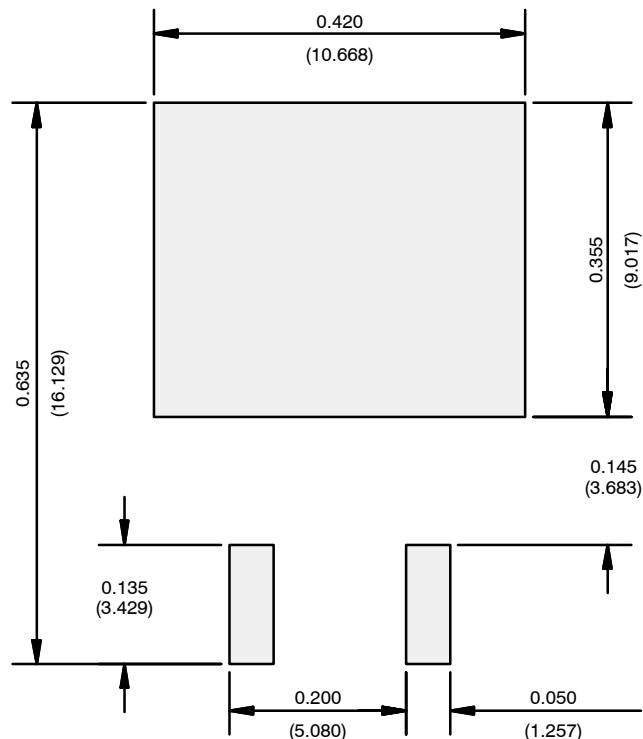
DIM.	INCHES		MILLIMETERS		
	MIN.	MAX.	MIN.	MAX.	
A	0.160	0.190	4.064	4.826	
b	0.020	0.039	0.508	0.990	
b1	0.020	0.035	0.508	0.889	
b2	0.045	0.055	1.143	1.397	
c*	Thin lead	0.013	0.018	0.330	0.457
	Thick lead	0.023	0.028	0.584	0.711
c1	Thin lead	0.013	0.017	0.330	0.431
	Thick lead	0.023	0.027	0.584	0.685
c2	0.045	0.055	1.143	1.397	
D	0.340	0.380	8.636	9.652	
D1	0.220	0.240	5.588	6.096	
D2	0.038	0.042	0.965	1.067	
D3	0.045	0.055	1.143	1.397	
E	0.380	0.410	9.652	10.414	
E1	0.245	-	6.223	-	
E2	0.355	0.375	9.017	9.525	
E3	0.072	0.078	1.829	1.981	
e	0.100 BSC		2.54 BSC		
K	0.045	0.055	1.143	1.397	
L	0.575	0.625	14.605	15.875	
L1	0.090	0.110	2.286	2.794	
L2	0.040	0.055	1.016	1.397	
L3	0.050	0.070	1.270	1.778	
L4	0.010 BSC		0.254 BSC		
M	-	0.002	-	0.050	

ECN: T10-0738-Rev. J, 03-Jan-11

DWG: 5843

#### Notes

1. Plane B includes maximum features of heat sink tab and plastic.
  2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
  3. Pin-to-pin coplanarity max. 4 mils.
  4. \*: Thin lead is for SUB, SYB.  
Thick lead is for SUM, SYM, SQM.
  5. Use inches as the primary measurement.
- This feature is for thick lead.

**RECOMMENDED MINIMUM PADS FOR D<sup>2</sup>PAK: 3-Lead**

Recommended Minimum Pads  
Dimensions in Inches/(mm)

[Return to Index](#)



### Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

### Material Category Policy

**Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.**

**Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.**

**Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.**

ООО "ЛайфЭлектроникс"

"LifeElectronics" LLC

ИНН 7805602321 КПП 780501001 Р/С 40702810122510004610 ФАКБ "АБСОЛЮТ БАНК" (ЗАО) в г.Санкт-Петербурге К/С 30101810900000000703 БИК 044030703

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибуторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибуторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помочь разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)  
Email: org@lifeelectronics.ru